



Mini-Circuits®

MMIC SURFACE MOUNT

Monolithic Amplifier

LEE-9+**50Ω DC to 8 GHz**

THE BIG DEAL

- Frequency Range, DC to 8 GHz
- Internally Matched to 50Ω
- Gain, 8.4 dB Typ. at 2 GHz
- Outstanding Gain Flatness, ±0.5 dB Typ.
- Output Power, +13.9 dBm Typ. at 2 GHz
- Aqueous Washable
- Protected By US Patent 6,943,629

*Generic photo used for illustration purposes only*

CASE STYLE: FG873

+RoHS Compliant

The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

APPLICATIONS

- Cellular
- PCS
- Communication Receivers & Transmitters
- Satellite Communication, Military

PRODUCT OVERVIEW

LEE-9+ (RoHS compliant) is wideband current driven amplifier fabricated using HBT technology. In addition, the LEE-9+ has good input and output return loss over a broad frequency range without the need for external matching components. Lead finish is SnAgNi. It has repeatable performance from lot to lot and is enclosed in a 3 mm x 3 mm x 0.89 mm MCLP package for very good thermal performance.

KEY FEATURES

Feature	Advantages
Broadband, DC* to 8 GHz	A single amplifier covering DC* to C band. <ul style="list-style-type: none"> • Reduced component inventory • Ideal for wideband applications such as instrumentation and military
Low Gain: 8.5 dB Typ. at 0.1 GHz and 7.7 dB at 8 GHz	Ideal for increasing the gain of amplifier chain by low value. Typically small gain change may need two components; an amplifier and an attenuator. Use of LEE-9+ reduces component count.
Outstanding Gain Flatness: ±0.4 dB	No need for gain flatness compensation over 8 GHz band to realize published gain flatness.
Wideband Matched Input Return Loss: 17-29 dB Typ. Output Return Loss: 12-34 dB Typ.	No external matching required to realize published return loss.
MCLP Package	Low inductance, repeatable transitions, excellent thermal pad.

* Low frequency cut off determined by external coupling capacitors.





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ELECTRICAL SPECIFICATIONS¹ AT +25°C AND 50 mA UNLESS NOTED OTHERWISE

Parameter	Conditions (GHz)	Min.	Typ.	Max.	Units
Frequency Range ²		DC		8	GHz
Gain	0.1	7.6	8.5	9.3	dB
	1		8.5		
	2		8.4		
	4		8.2		
	5		8.0		
	8		7.7		
Input Return Loss	0.1		24.0		dB
	1		23.8		
	2		22.6		
	4		20.2		
	5		23.1		
	8		23.5		
Output Return Loss	0.1		33.0		dB
	1		29.7		
	2		26.1		
	4		22.0		
	5		20.9		
	8		13.3		
Output Power @ 1 dB Compression	0.1	+12.0	+14.1		dBm
	1		+14.0		
	2		+13.9		
	4		+12.4		
	5		+11.9		
	8		+7.9		
Output IP3	0.1		+31.3		dBm
	1		+30.5		
	2		+29.7		
	4		+25.4		
	5		+23.4		
	8		+19.7		
Noise Figure	0.1		5.1		dB
	1		5.1		
	2		5.3		
	4		5.3		
	5		5.2		
	8		5.3		

1. Measured on Mini-Circuits test board TB-154.

2. Low frequency cut off determined by external coupling capacitors.





Monolithic Amplifier

50 Ω DC to 8 GHzELECTRICAL SPECIFICATIONS¹ AT +25°C AND 50 mA UNLESS NOTED OTHERWISE

Parameter	Conditions (GHz)	Min.	Typ.	Max.	Units
Recommended Device Operating Current (I_D)			50		mA
Device Operating Voltage (V_D)		+3.6	+4.0	+4.4	V
Device Voltage Variation vs. Temperature at 50 mA			-2.7		mV/°C
Device Voltage Variation vs. Current at +25°C			17.3		mV/mA
Thermal Resistance, Junction-to-Case ³			138		°C/W

3. Case is defined as ground leads.

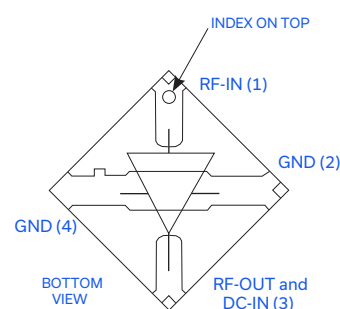
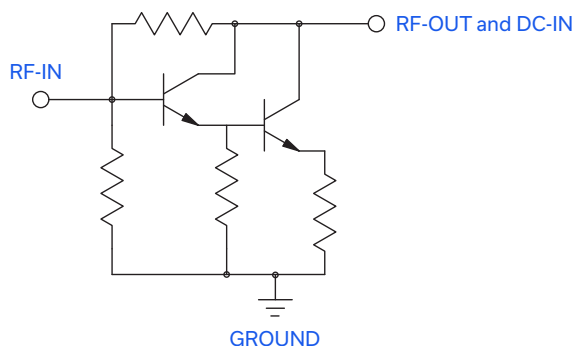
ABSOLUTE MAXIMUM RATINGS⁴

Parameter	Ratings
Operating Temperature (Ground Lead)	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Operating Current	74 mA
Input Power ⁵	+26 dBm (5 min max.) +15 dBm (continuous)

4. Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

5. For continuous operation +15 dBm max.

SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION



Function	Pin Number	Description
RF-IN	1	RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.
RF-OUT and DC-IN	3	RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit".
GND	2,4	Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.



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CHARACTERIZATION TEST CIRCUIT

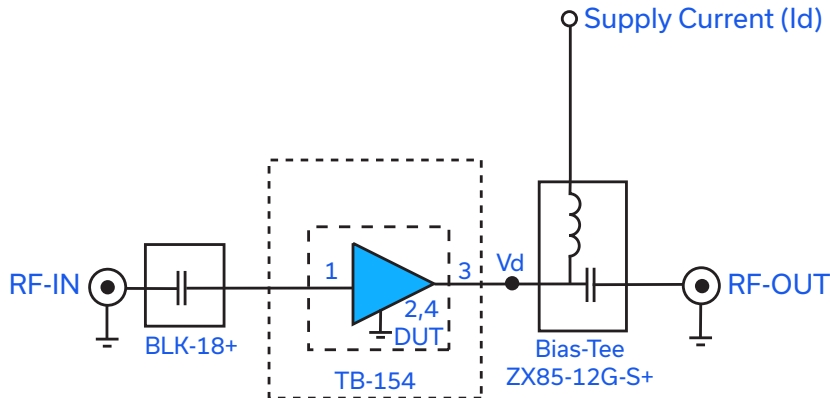
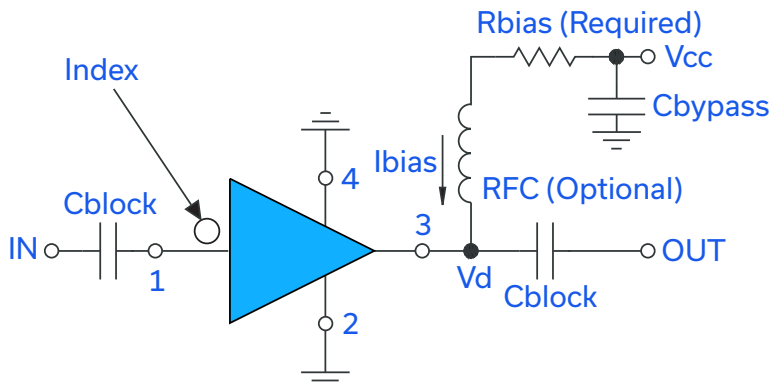


Fig 1. Block Diagram of Test Circuit used for characterization. (DUT soldered on Mini-Circuits Characterization test board TB-154)
Gain, Return Loss, Output Power at 1 dB Compression (P1dB), Output IP3 (OIP3) and Noise Figure measured using Agilent's N5242A PNA-X microwave network analyzer.

Conditions:

1. Gain and Return loss: $P_{IN} = -25$ dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, -5 dBm/tone at output.

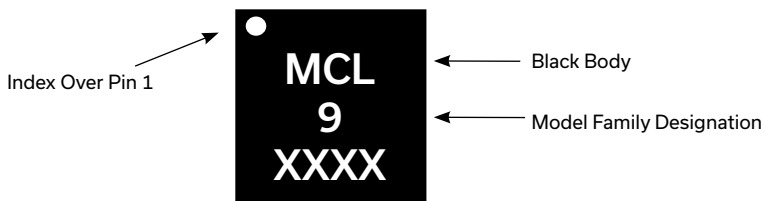
RECOMMENDED APPLICATION CIRCUIT



Test Board includes case, connectors, and components (in bold) soldered to PCB

R BIAS	
Vcc	"1%" Res. Values (Ohms) for Optimum Biasing
7	61.9
8	80.6
9	100
10	121
11	140
12	165
13	182
14	200
15	221
16	237
17	261
18	274
19	301
20	316

PRODUCT MARKING



Markings in addition to model number designation may appear for internal quality control purposes.





ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. [CLICK HERE](#)

Performance Data & Graphs	Data Table
	Swept Graphs
	S-Parameter (S2P Files) Data Set (.zip file)
Case Style	FG873 Plastic package, exposed paddle, Lead finish: Matte-Tin
Tape & Reel Standard Quantities Available on Reel	F68 7" Reels with 20, 50, 100, 200, 500 or 1K devices 13" Reels with 2K, 3K, 4K devices
Suggested Layout for PCB Design	98-PL-252
Evaluation Board	TB-413-9+
Environmental Ratings	ENV08T1

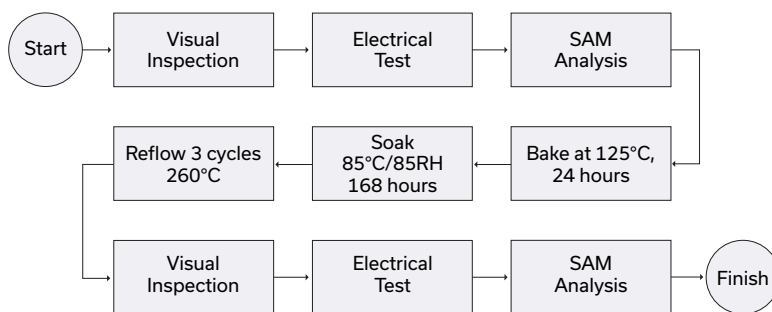
ESD RATING

Human Body Model (HBM): Class 1B (500 V to <1000 V) in accordance with ANSI/ESD STM 5.1 - 2001

Machine Model (MM): Class M1 (<25 V) in accordance with ESD STM 5.2 - 1999

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020D

MSL TEST FLOW CHART**NOTES**

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuits' applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits' standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html